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**General Description:**

Npn phototransistor; pn infrared emitting diode; gallium arsenide led; silicon photo darlington transistor; 250 mw; 80 ma; 30 volts; minus 55 degrees c to plus 100 degrees c operating junction temperature range; 6 terminals; 0.350 in. Lg; 0.300 in. W; 0.200 in. H

**Specification Data:**

80131-release 6464 professional/industrial association specification

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

Yes - demil/mli

**Fig:**

A23900